NSN 5961-00-153-7302

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-153-7302 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 250.0 breakdown voltage, collector-to-base, emitter open and 6.0 breakdown voltage, emitter-to-base, collector open and 225.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 250.00 milliamperes source cutoff current and 500.00 milliamperes base current, dc **Power Rating Per Characteristic:** 133.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: